## NSN 5961-01-318-0121

Transistor - Page 1 of 1

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-318-0121 **Inclosure Material:** Ceramic **Overall Length:** 1.8 millimeters **Overall Height:** 12.0 millimeters **Overall Width:** 12.0 millimeters **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 18.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No